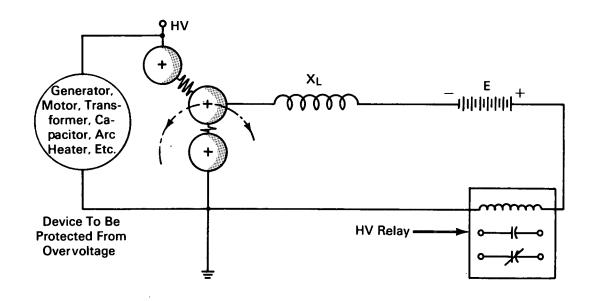
December 1966

NASA TECH BRIEF

NASA Tech Briefs are issued to summarize specific innovations derived from the U.S. space program, to encourage their commercial application. Copies are available to the public at 15 cents each from the Clearinghouse for Federal Scientific and Technical Information, Springfield, Virginia 22151.

Trisphere Spark Gap Actuates Overvoltage Relay



The problem:

To provide a positive, fast response, high current capacity device that will sense an overvoltage condition and remove power from the circuit before insulation breakdown.

The solution:

A trisphere spark gap and high voltage relay so arranged that when an overvoltage occurs, the spark gap breaks down and conducts an actuating current to the relay which removes power from the circuit.

How it's done:

Three 1 1/4-inch copper spheres are mounted on 1/4-inch brass rods to a section of dielectric material. The center sphere is located in relation to the grounded sphere so that a constant 1/8-inch gap is maintained between them, while spacing between the

center and high voltage spheres may be varied. Connected in series between the center and grounded spheres are a high voltage relay, a battery and a small choke coil.

When the high voltage sphere (which is integral to the circuit being protected) reaches a predetermined potential, the gaps will break down and current will flow between the three spheres. Because of the choke in the relay circuit, both gaps will break down simultaneously and the ionized path between the center and grounded spheres completes the relay circuit and energizes the relay. The relay contacts remove the source of high voltage to the protected circuit and the trisphere spark gap/relay device is automatically returned to its passive condition.

(continued overleaf)

This document was prepared under the sponsorship of the National Aeronautics and Space Administration. Neither the United States Government nor any person acting on behalf of the United States Government assumes any liability resulting from the use of the information contained in this document, or warrants that such use will be free from privately owned rights.

Note:

Inquiries concerning this invention may be directed to:

Technology Utilization Officer Ames Research Center Moffett Field, California 94035 Reference: B66-10557

Patent status:

Inquiries about obtaining rights for the commercial use of this invention may be made to NASA, Code GP, Washington, D.C. 20546.

Source: Salvador L. Camacho (ARC-68)

Category 01